

Features

- High density cell design for ultra low $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

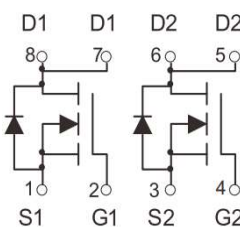
- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

Product Summary

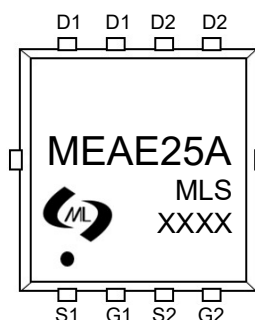
V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
40V	13mΩ@10V	25A
	20mΩ@4.5V	



PDFN3X3-8L view



Schematic diagram



MEAE25A : Device code
XXXX : Code

Marking and pin assignment



Halogen-Free

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Rating	Unit
Common Ratings ($T_C=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DS}	Drain-Source Breakdown Voltage	40	V
V_{GS}	Gate-Source Voltage	± 20	V
T_J	Maximum Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-50 to 155	$^\circ\text{C}$
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 25	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ 100	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ 25	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 5	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	136	$^\circ\text{C/W}$

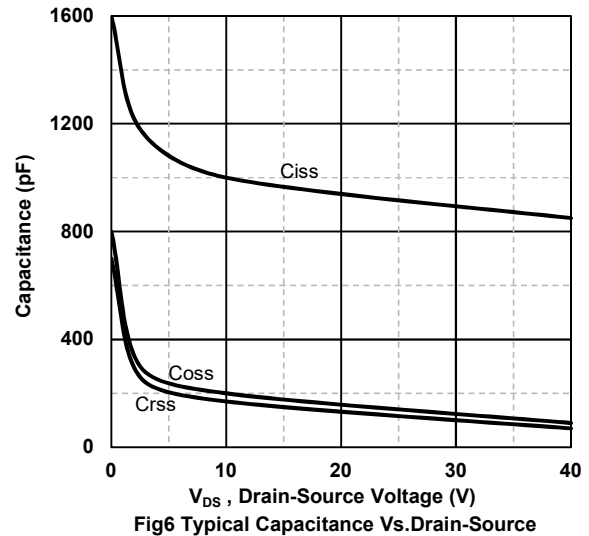
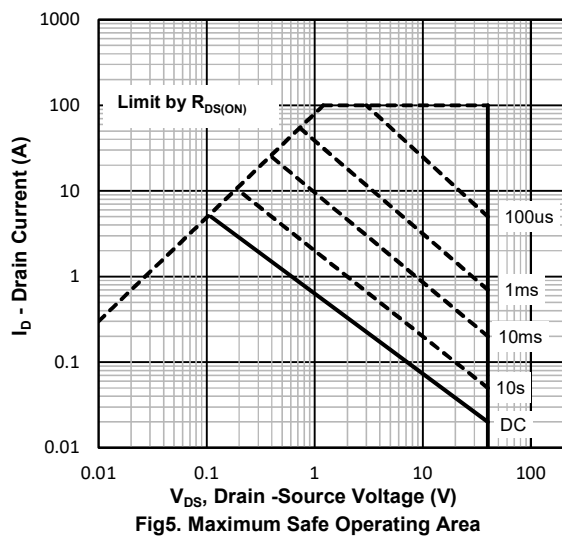
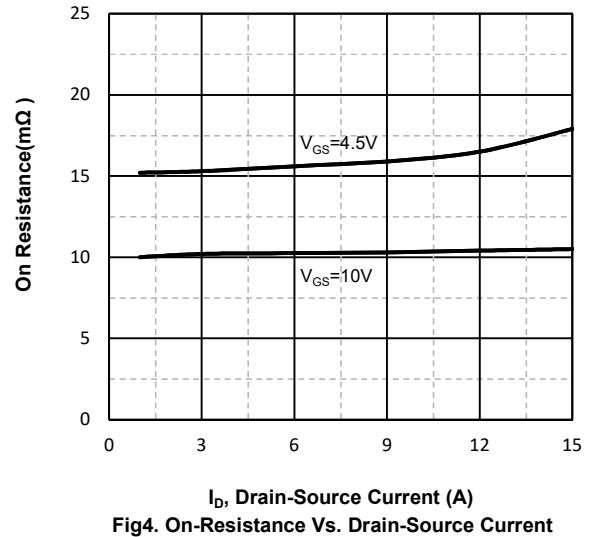
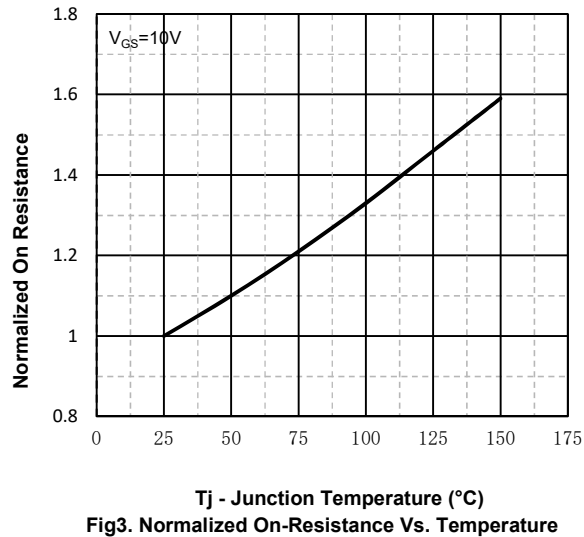
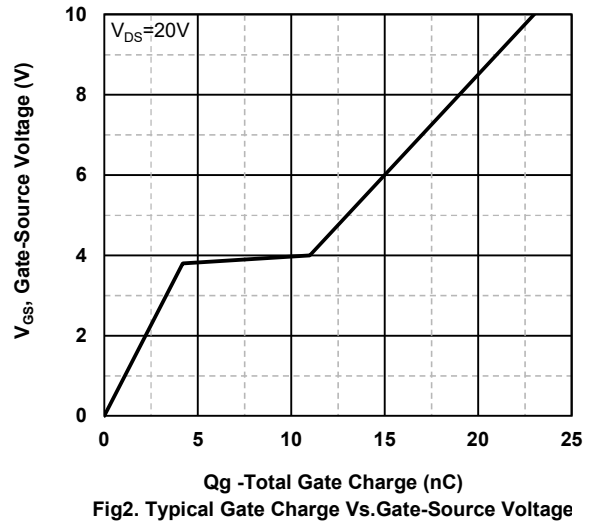
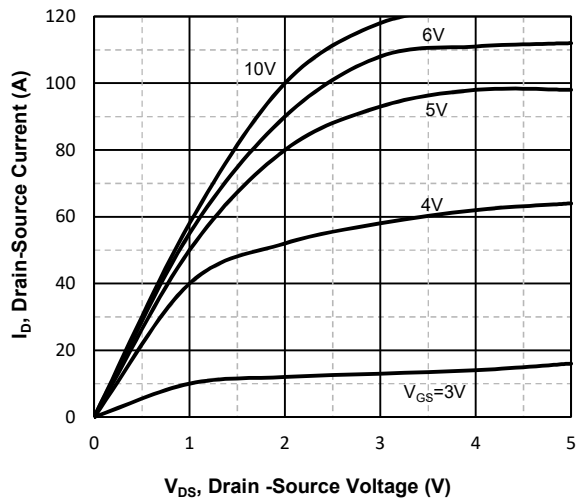
Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MEAE25A	PDFN3X3-8L	MEAE25A	5,000	10,000	70,000	13"reel

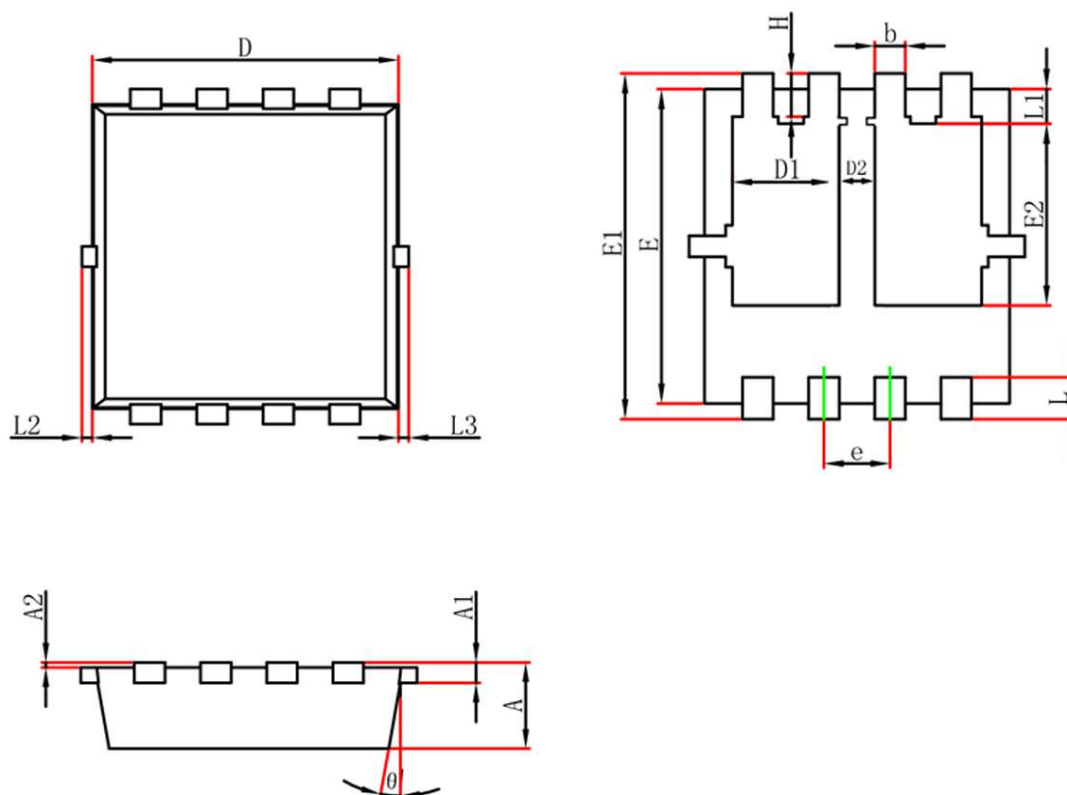
Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	40	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=40V, VGS=0V	--	--	1	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=250μA	1.0	1.5	2.5	V
RDS(on)	Drain-Source On-State Resistance	VGS=10V, ID=25A	--	10	13	mΩ
		VGS=4.5V, ID=15A	--	15	20	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
CISS	Input Capacitance	VDS=20V, VGS=0V, f=1MHz	--	917	--	pF
COSS	Output Capacitance		--	128	--	pF
CRSS	Reverse Transfer Capacitance		--	108	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDD=20V, ID=25A, VGS=10V	--	23.6	--	nC
Qgs	Gate Source Charge		--	4.4	--	nC
Qgd	Gate Drain Charge		--	6.3	--	nC
tD(on)	Turn-on Delay Time	VDD=10V, ID=25A, VGS=4.5V, RG=3Ω	--	10	--	nS
tR	Turn-on Rise Time		--	56	--	nS
tD(off)	Turn-Off Delay Time		--	27	--	nS
tF	Turn-Off Fall Time		--	72	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, IS=25A	--	--	1.2	V

Typical Operating Characteristics



PDFN3X3-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.750	0.850	0.030	0.034
A1	0.152 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	3.050	3.150	0.121	0.125
D1	0.985	1.085	0.039	0.043
D2	0.330	0.430	0.013	0.017
E	2.950	3.050	0.117	0.121
E1	3.250	3.350	0.129	0.132
E2	1.685	1.785	0.067	0.071
b	0.250	0.350	0.010	0.014
e	0.600	0.700	0.024	0.028
L	0.350	0.450	0.014	0.018
L1	0.280	0.380	0.011	0.015
L2	0~0.100		0~0.004	
L3	0~0.100		0~0.004	
H	0.350	0.450	0.014	0.018
θ	9°	13°	10°	12°